

RED DIODE LASER AT 760nm

RN-H-760/1~3000mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy operation.

They are widely used in measurement, spectrum analysis, etc.

产品参数

| RN-H-760/1~3000mW | |
|---|--|
| Central wavelength (nm) | 760±10 |
| Operating mode | CW |
| Output power (mW) | >1, 500, 1000, ... , 3000 |
| Power stability (rms, over 4 hours) | <1%, <2%, <3% (<0.5%, optional) |
| Transverse mode | Multimode |
| Dimensions of beam at the aperture (mm) | ~5×8 |
| Beam divergence, full angle (mrad) | <3. 0 |
| Warm-up time (minutes) | <5 |
| Beam height from base plate (mm) | 29 |
| Operating temperature (°C) | 10~35 |
| Power supply (100-240VAC) | PSU-H-LED PSU-H-FDA |
| TTL / Analog modulation | TTL or Analog with 1Hz-1KHz 1KHz-10KHz, 10KHz-30KHz optional |
| Expected lifetime (hours) | 10000 |
| Warranty | 1 year |